## NSN 5962-01-230-9597

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## **Body Length:** 1.490 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.0 watts **Operating Tempurature Range:** -55.0 to 125.0 degrees celsius Storage Tempurature Range: -65.0 to 150.0 degrees celsius **Features Provided:** Programmable and monolithic and ultraviolet erasable and hermetically sealed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-10 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Time Rating Per Chacteristic:** 450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 printed circuit Shelf Life: N/a Unit Of Measure: ---**Demilitarization:**

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Yes - demil/mli
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**Fiig:** A458a0

